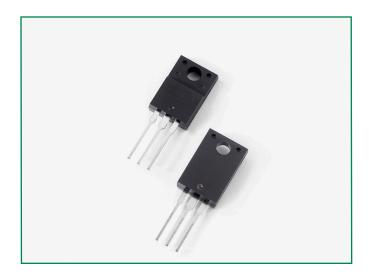


DURF1060CT









Description

Littelfuse DUR series Ultrafast Recovery Rectifier is designed to meet the general requirements of commercial applications by providing low Trr, high-temperature, low-leakage and low forward voltage drop products. It is suitable for output rectifier, free-wheeling or boost diode in high-frequency power switching application such as switch mode power supply and DC-DC converters.

Features

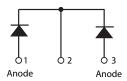
- Ultra-fast switching
- Low reverse leakage current
- High surge current capability
- Low forward voltage drop
- Common Cathode

configuration in electrically isolated ITO-220AB package

 Pb-free E3 means 2nd level interconnect is Pbfree and the terminal finish material is tin(Sn) (IPC/ JEDEC J-STD-609A.01)

Circuit Diagram

Base Common Cathode



Applications

- Output rectifiers in switch mode power supplies (SMPS) and DC to DC converters
- Free-wheeling diode or boost diode in converters and motor control circuits
- Anti-parallel diode for high frequency switching devices such as IGBT
- Uninterruptible Power Supplies (UPS)
- Inductive heating and melting
- Ultrasonic cleaners and welders

Maximum Ratings

Characteristics	Symbol	Conditions	Max.	Unit
Peak Inverse Voltage	V _{RWM}	-	600	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =100 °C, rectangular wave form	5 (Per Leg)	- A
			10 (Total Device)	
Peak One Cycle Non- Repetitive Surge Current (Per Leg)	I _{FSM}	8.3 ms, half sine pulse	60	А

Electrical Characteristics

Characteristics	Symbol	Conditions	Max.	Unit
Forward Voltage Drop (Per Leg) ¹	V _{F1}	@5A, Pulse, T _J = 25 °C	1.55	V
	V _{F2}	@5A, Pulse, T _J = 125 °C	1.45	V
Reverse Current (Per Leg) ¹	I _{R1}	$@V_R = Rated V_R, T_J = 25 °C$	5	μΑ
	I _{R2}	$@V_R = Rated V_R, T_J = 125 °C$	500	μΑ
Reverse Recovery Time	t _{m1}	$I_F = 500 \text{mA}, I_R = 1 \text{A}, \text{and } I_m = 250 \text{mA}$	50	ns

Footnote 1 : Pulse Width $< 300 \mu s$, Duty Cycle < 2%

Thermal-Mechanical Specifications

Characteristics	Symbol	Conditions	Specification	Unit
Junction Temperature	T	-	-55 to +150	°C
Storage Temperature	T _{stq}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _{eJC}	DC operation	5.0	°C/W
Approximate Weight	wt	-	2.0	g
Case Style	_	ITO-220AB	-	-

Figure 1: Typical Forward Characteristics

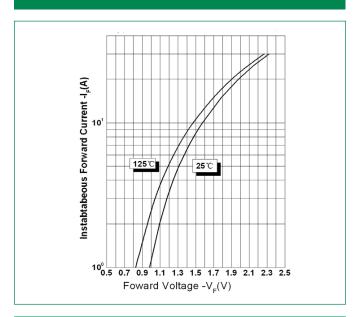


Figure 3: Typical Junction Capacitance

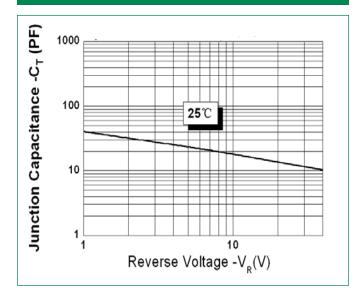
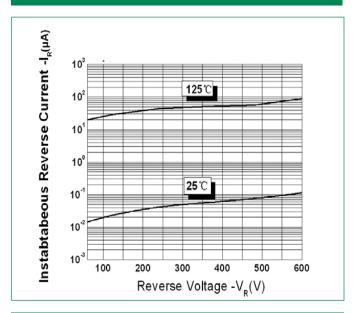
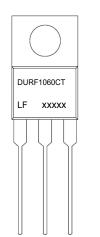


Figure 2: Typical Reverse Characteristics



Part Numbering and Marking System

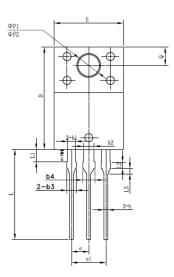


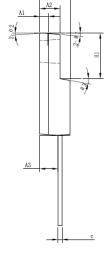
DUR	= Device Type
F	= Package type
10	= Forward Current (10A)
60	= Reverse Voltage (600V)
CT	= Configuration
LF	= Littelfuse
YY	= Year
WW	= Week
Ľ	= Lot Number



Packing Options				
Part Number	Marking	Packing Mode	M.O.Q	
DURF1060CT	DURF1060CT	50pcs / Tube	1000	

Dimensions-Package ITO-220AB







Symbol	Millimeters			
Symbol	Min	Тур	Max	
А	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.55	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
øP1	3.30	3.50	3.70	
øP2	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
θ1		5°		
θ2		4°		
θ3		10°		
θ4		5°		
θ5		5°		

Tube Specification ITO-220AB

